

27C512

512K (64K x 8) CMOS EPROM

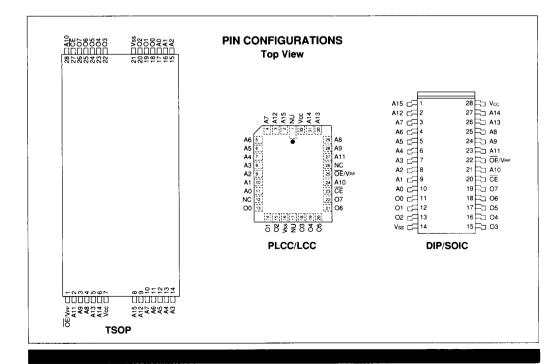
FEATURES

- High speed performance
 —90ns access time available
- · CMOS Technology for low power consumption
 - -35mA Active current
 - -100µA Standby current
- · Factory programming available
- · Auto-insertion-compatible plastic packages
- Auto ID™ aids automated programming
- · High speed express programming algorithm
- · Organized 64K x 8: JEDEC standard pinouts
- -28-pin Dual-in-line package
- -32-pin Chip carrier (leadless or plastic)
- -28-pin SOIC package
- -28-pin TSOP
- -Tape and reel
- · Available for the following temperature ranges:
 - --Commercial: 0° C to 70° C --Industrial: -40° C to 85° C --Automotive: -40° C to 125° C

DESCRIPTION

The Microchip Technology Inc. 27C512 is a CMOS 512K bit (electrically) Programmable Read Only Memory. The device is organized into 64K words by 8 bits (64K bytes). Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 90ns. This very high speed device allows the most sophisticated microprocessors to run at full speed without the need for WAIT states. CMOS design and processing enables this part to be used in systems where reduced power consumption and high reliability are requirements.

A complete family of packages is offered to provide the most flexability in applications. For surface mount applications, PLCC or SOIC packaging is available. Tape or reel packaging is also available for PLCC or SOIC packages. UV erasable versions are also available.



PIN FUNCTI	PIN FUNCTION TABLE								
Name	Function								
A0 - A15	Address Inputs								
CE	Chip Enable								
OE/VPP	Output Enable/								
	Programming Voltage								
O0 - O7	Data Output								
Vcc	+5V Power Supply								
Vss	Ground								
NC	No Connection; No Internal								
	Connection								
NU	Not Used; No External								
	Connection Is Allowed								

ELECTRICAL CHARACTERISTICS

Maximum Ratings*

Vcc and input voltages w.r.t. Vss.....-0.6V to +7.25V VPP voltage w.r.t. Vss during programming-0.6V to +14.0V Voltage on A9 w.r.t. Vss-0.6V to +13.5V Output voltage w.r.t. Vss-0.6V to Vcc + 1.0V Storage temperature-65° C to 150° C Ambient temp. with power applied-65° C to 125° C

*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

READ OPERATION	
DC Characteristics	

 $Vcc = +5V \pm 10\%$

Commercial: Industrial:

Tamb= 0° C to 70° C Tamb= -40° C to 85° C

Extended (Automotive):

Tamb= -40° C to 125° C

Parameter	Part*	Status	Symbol	Min	Max	Units	Conditions
Input Voltages	all	Logic "1"	ViH	2.0	Vcc+1	V	
		Logic "0"	VIL	-0.5	0.8	V	
Input Leakage	all		lL1	-10	10	μA	VIN= 0 to VCC
Output Voltages	all	Logic "1"	Vон	2.4		V	IOH = -400μA
	ł	Logic "0"	Vol		0.45	l v	loL = 2.1mA
Output Leakage	all		lLO	-10	10	μА	Vout = 0V to Vcc
Input Capacitance	all		Cin		6	pF	VIN = 0V; Tamb = 25° C f = 1MHz
Output Capacitance	all		Соит		12	pF	Vout = 0V;Tamb= 25° (f = 1MHz
Power Supply Current,	С	TTL input	lcc		35	mA	Vcc = 5.5V
Active	I, E	TTL input	Icc		45	mA	$\begin{split} & \underbrace{f = 1 \text{MHz};}_{OE/VPP=CE} = \text{ViL}; \\ & \text{lout} = 0 \text{mA}; \\ & \text{ViL} = -0.1 \text{ to } 0.8 \text{ V}; \\ & \text{ViH} = 2.0 \text{ to } \text{Vcc}; \end{split}$
		···				.	Note (1)
Power Supply Current,	C_	TTL input	ICC(S)TTL		2	mA	
Standby	I, E	TTL input	ICC(S)TTL		3	mA	<u> </u>
	C_	CMOS input	ICC(S)CMOS		100	μA	$\overline{CE} = Vcc \pm 0.2V$

C = Commercial Temperature Range; I, E = Industrial and Extended Temperature Ranges Notes: (1) Active current increases 2 mA per MHz up to operating frequency for all temperature ranges. **READ OPERATION AC Characteristics**

AC Testing Waveform:

VIH = 2.4V and VIL = .45V; VOH = 2.0V and VOL = 0.8V

Output Load:

1 TTL Load + 100pF

Input Rise and Fall Times: 10nsec Ambient Temperature:

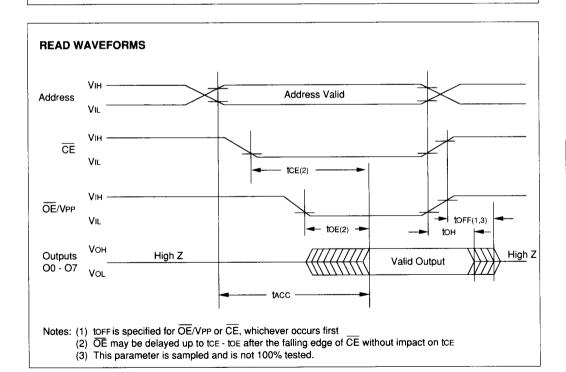
Commercial:

Tamb = 0° C to 70° C Tamb = -40° C to 85° C

Industrial: Extended (Automotive): Tamb = -40° C to 125° C

Parameter	Sym	27C	512-90	27C	512-1	027C	512-1	227C	512-1	527C	512-20) Units	Conditions
		Min	Мах	Min	Max	Min	Мах	Min	Мах	Min	Мах		
Address to Output Delay	tacc		90		100		120		150		200	ns	CE = OE/VPP = VIL
CEto Output Delay	tCE		90		100		120		150		200	ns	OE/VPP = VIL
OE to Output Delay	tOE		40		40		50		60		75	ns	CE = VIL
OE to Output High Impedance	toff	0	35	0	35	0	40	0	45	0	55	ns	
Output Hold from Address, CE or OE/VPP, whichever occured first	tон	0		0		0		0		0		ns	

 * -90 AC Testing Waveform: VIH = 2.4V and VIL = .45V; VOH = 1.5V and VOL = 1.5V Output Load: 1 TTL Load + 30pF



PROGRAMMING DC Characteristics	Ambient Temperature: 25° C \pm 5° C VCC = 6.5V \pm 0.25V, OE/VPP = VH = 13.0V \pm 0.25V									
Parameter	Status	Symbol	Min	Max	Units	Conditions (See Note 1				
Input Voltages	Logic "1"	ViH	2.0	Vcc+1	V					
	Logic "0"	VIL	-0.1	0.8	v					
Input Leakage		lLi	-10	10	μА	VIN = 0V to VCC				
Output Voltages	Logic "1"	Vон	2.4		V	IOH = -400μA				
	Logic "0"	Vol		0.45	v	IOL = 2.1mA				
Vcc Current, program & verify		ICC2		35	mA					
OE/VPP Current, program		IPP2		25	mA	CE = VIL				
A9 Product Identification		VID	11.5	12.5	V					

Note: (1) Vcc must be applied simultaneously or before the VPP voltage on $\overline{\text{OE}}/\text{VPP}$ and removed simultaneously or after the VPP voltage on $\overline{\text{OE}}/\text{VPP}$.

PROGRAMMING AC Characteristics

AC Testing Waveform: VIH= 2.4V and VIL= 0.45V; VOH= 2.0V; VOL = 0.8V

Ambient Temperature: 25° C ±5° C

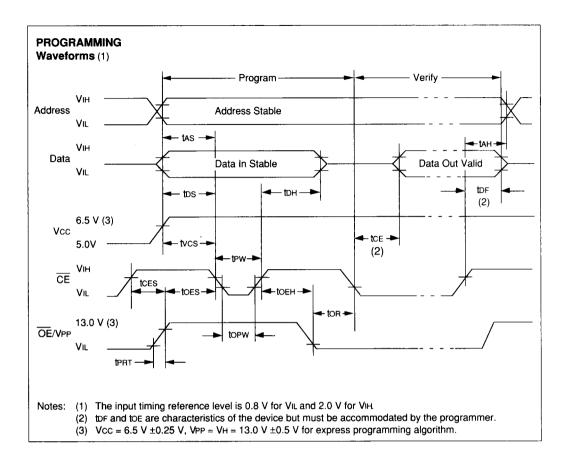
for Program, Program Verify and Program Inhibit Modes

 $\text{VCC} = 6.5 \text{V} \pm 0.25 \text{V}, \, \underline{\text{OE}}/\text{VPP} = \text{VH} = 13.0 \text{V} \pm 0.25 \text{V}$

Parameter	Symbol	Min	Max	Units	Remarks
Address Set-Up Time	tas	2		μs	
Data Set-Up Time	tos	2		μѕ	-
Data Hold Time	toн	2		μѕ	
Address Hold Time	tан	0		μs	
Float Delay (2)	tor	0	130	ns	
Vcc Set-Up Time	tvcs	2		μs	
Program Pulse Width (1)	tpw	95	105	μs	100µs typical
CE Set-Up Time	tces	2		μs	-
OE Set-Up Time	toes	2		μS	
OE Hold Time	toeh	2		μs	
OE Recovery Time	ton	2		μs	
OE/VPP Rise Time During Programming	t _{PRT}	50		ns	

Notes: (1) For express algorithm, initial programming width tolerance is $100\mu sec \pm 5\%$.

(2) This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).



MODES

Operation Mode	CE	ÖE/VPP	A9	O0 - O7
Read Program Program Verify Program Inhibit Standby Output Disable	VIL VIL VIH VIH VIL	VIL VH VIL VH X VIH	X X X X	DOUT DIN DOUT High Z High Z High Z
Identity	VIL	VIL	Vн	Identity Code

X = Don't Care

Read Mode

(See Timing Diagrams and AC Characteristics)

Read Mode is accessed when

- a) the $\overline{\text{CE}}$ pin is low to power up (enable) the chip
- b) the $\overline{\text{OE}}/\text{VPP}$ pin is low to gate the data to the output pins.

For Read operations, if the addresses are stable, the address access time (tACC) is equal to the delay from CE to output (tCE). Data is transferred to the output after a delay (tOE) from the falling edge of \overline{OE} /VPP.

Standby Mode

The standby mode is defined when the $\overline{\text{CE}}$ pin is high and a program mode is not identified.

When this condition is met, the supply current will drop from 35mA to $100\mu A$.

Output Enable OE/VPP

This multifunction pin eliminates bus connection in multiple bus microprocessor systems and the outputs go to high impedance when:

• the OE/VPP pin is high (VIH).

When a VH input is applied to this pin, it supplies the programming voltage (VPP) to the device.

Erase Mode (UV Windowed Versions)

Windowed products offer the ability to erase the memory array. The memory matrix is erased to the all "1's" state as a result of being exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/cm² is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of $12,000\mu W/cm²$ for approximately 20 minutes.

Programming Mode

The Express algorithm has been developed to improve on the programming throughput times in a production environment. Up to 10 100-microsecond pulses are applied until the byte is verified. A flowchart of the Express algorithm is shown in Figure 1.

Programming takes place when:

- a) Vcc is brought to the proper voltage,
- b) OE/VPP is brought to the proper VH level, and
- c) CE line is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0 - A15 and the data to be programmed is presented to pins O0 - O7. When data and address are stable, a low going pulse on the \overline{CE} line programs that location.

Verify

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- a) Vcc is at the proper level,
- b) the OE/VPP pin is low, and
- c) the CE line is low.

Inhibit

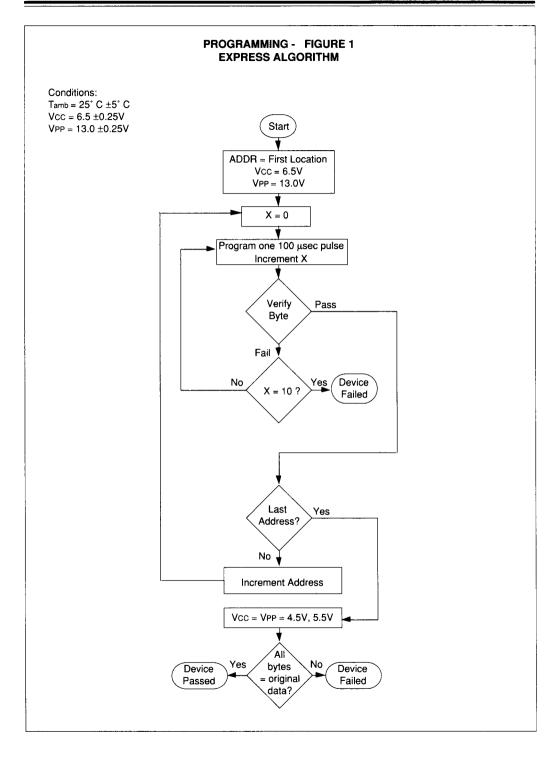
When programming multiple devices in parallel with different data, only \overline{CE} needs to be under separate control to each device. By pulsing the \overline{CE} line low on a particular device, that device will be programmed; all other devices with \overline{CE} held high will not be programmed with the data (although address and data will be available on their input pins).

Identity Mode

In this mode specific data is output which identifies the manufacturer as Microchip Technology Inc and the device type. This mode is entered when Pin A9 is taken to VH (11.5V to 12.5V). The CE and OE/VPP lines must be at VIL. A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin —►	Input	Output										
Identity	AO	O 7	O 6	0 5	0 4	O 3	0	0	00	H e x		
Manufacturer Device Type*	VIL VIH	00	0 0	1	0	1	0	0	1	29 0D		

^{*} Code subject to change.



SALES AND SUPPORT

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.

